## N-Channel 40-V (D-S) MOSFET

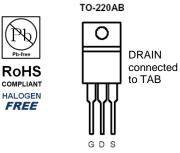
### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

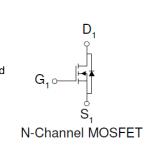
### **Typical Applications:**

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
40	5 @ V <sub>GS</sub> = 10V	90 <sup>a</sup>	
	$7.5 @ V_{GS} = 5.5V$	90	



Top View



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage			40	V		
Gate-Source Voltage			±20	V		
Continuous Drain Current a	T <sub>C</sub> =25°C	$I_D$	90	Α		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	360			
Continuous Source Current (Diode Conduction) <sup>a</sup>			90	Α		
Power Dissipation <sup>a</sup>	T <sub>C</sub> =25°C	$P_{D}$	300	W		
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	°C		

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	62.5	°C/W
Maximum Junction-to-Case	$R_{\theta JC}$	1	C/VV

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

### **Electrical Characteristics**

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current		$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
	I <sub>DSS</sub>	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	120			Α
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 45 \text{ A}$			5	mΩ
	r <sub>DS(on)</sub>	$V_{GS} = 5.5 \text{ V}, I_D = 40 \text{ A}$			7.5	
Forward Transconductance	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 20 \text{ A}$		30		S
Diode Forward Voltage	$V_{SD}$	$I_{S} = 55 \text{ A}, V_{GS} = 0 \text{ V}$		0.89		V
Dynamic						
Total Gate Charge	$Q_g$	$V_{DS} = 20 \text{ V}, V_{GS} = 5.5 \text{ V},$ $I_{D} = 20 \text{ A}$		69		nC
Gate-Source Charge	$Q_gs$			31		
Gate-Drain Charge	$Q_gd$	1D = 20 A		31		
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DS} = 20 \text{ V}, R_L = 1 \Omega,$ $I_D = 20 \text{ A},$ $V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		37		ns
Rise Time	t <sub>r</sub>			45		
Turn-Off Delay Time	t <sub>d(off)</sub>			112		
Fall Time	t <sub>f</sub>			39		
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		9569		
Output Capacitance	C <sub>oss</sub>			768		pF
Reverse Transfer Capacitance	$C_{rss}$			548		

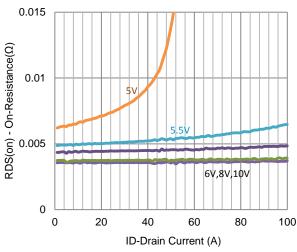
#### **Notes**

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

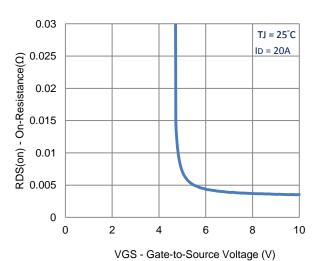
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### **Typical Electrical Characteristics**

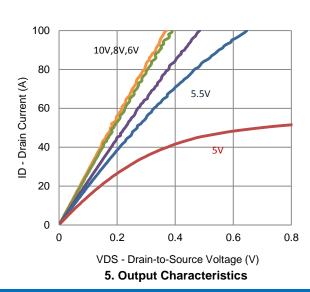
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#### 1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage



100
TJ = 25°C

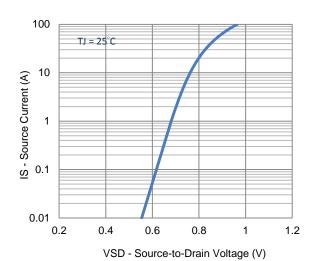
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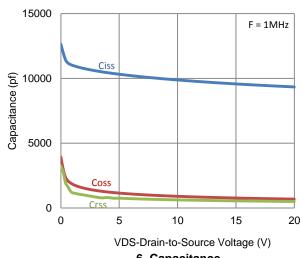
VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics

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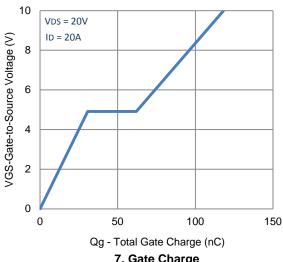
4. Drain-to-Source Forward Voltage



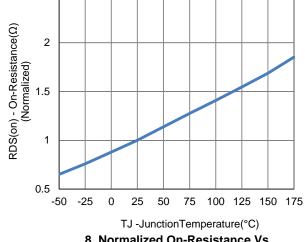
6. Capacitance

### **Typical Electrical Characteristics**

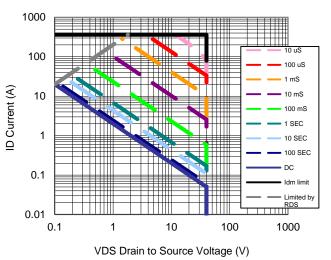
2.5



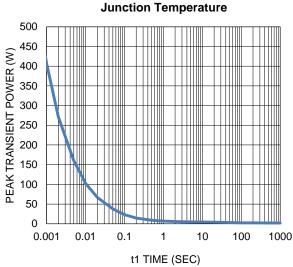




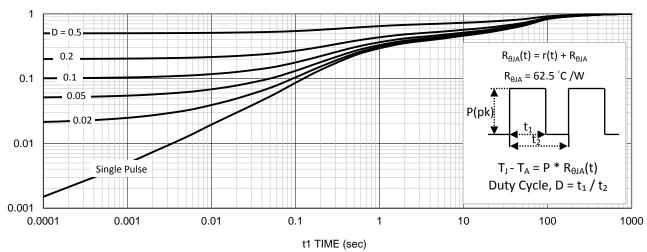
8. Normalized On-Resistance Vs



9. Safe Operating Area



10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

# **Package Information**

